

APPLICATION NOTE

VOLTAGE TO CURRENT WAVEFORM CONVERSION (Example Of The 10/700 μs Surge)

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INTRODUCTION

CCITT members have generated a great deal of recommendations which have permitted national

administrations to publish local standards. In particular they have defined a $10/700 \ \mu s$ surge waveform and its associated generator diagram (see fig.1).



Figure 1 : CCITT 10/700 μs Surge Definition



GENERATOR DIAGRAM OPEN OUTPUT SURGE WAVEFORM

It is important to note that the given waveform is the generator output voltage without load. For a protection component user the most important parameter to take into account is the current waveform flowing through the surge suppressor. The goal of this paper is to give the current waveform parameters.

2 - WAVEFORM CALCULATION

2.1 : Generator output voltage without load.

Figure 2 : Voltage Rise time



Figure 3 : Voltage duration



2.1.1 : Rise time

The equation of this curve is :

$$v(t) = Vp (1 - exp (- t/T))$$

 $\Rightarrow t = -T \log_n (1 - (v(t)/Vp))$ (1)

In this case the time constant may be estimated as :

 $\begin{array}{l} \mathsf{T} = \mathsf{R}_2 \ \mathsf{C}_2 \\ \text{So t}(0.3) \ \text{and t}(0.9) \ \text{will be calculated} \\ \text{respectively with } \mathsf{v}(t)/\mathsf{Vp} = 0.3 \ \text{and } 0.9 \\ \mathsf{t}(0.3) = 1 \ \mu s \\ \mathsf{t}(0.9) = 6.9 \ \mu s \\ \text{and then} \\ \texttt{t1} = 1.67 \ (\mathsf{t}_{(0.9)} - \mathsf{t}_{(0.1)}) \\ = 9.8 \ \mu s \\ \underline{\approx 10 \ \mu s} \end{array}$

2.1.2 : Voltage surge duration The equation of this curve is:

v(t) = Vp exp (-t/T))

$$\Rightarrow$$
 t = - log_n (v(t)/Vp)) (2)

with a time constant due essentially to $R_1 \mbox{ and } C_1$

 $\label{eq:tau} \begin{array}{l} T = R_1 \ C_1 \\ \text{So } t_2 \ \text{may be calculated with} \\ v(t)/Vp = 0.5 \end{array}$

2.2 Generator short circuted output current.

In this chapter we will do the calculations with the generator output in short circuit (see fig.4), this is generally the case during the surge suppressor action (for example the Trisil technogy devices from SGS THOMSON).



Figure 4 : CCITT 10/700 ms generator with output in short circuit

2.2.1 : Rise time





The formula (1) given in the chapter 2.1.1. remains true, but the time constant must take into account $R_3\,$ and may be estimated as :

$$T = (R_2 R_3/(R_2 + R_3)) C_2$$

So $t_{(0.3)} = 0.67 \ \mu s$
 $t_{(0.9)} = 4.3 \ \mu s$
 $\Rightarrow t1 = 1.67 (t(0.9) - t(0.1))$
 $= 6 \ \mu s \ \underline{\approx 5 \ \mu s}$

2.1.2 : Current surge duration.

Figure 6 : Current duration



The formula (2) given in the chapter 2.1.2. remains true but the time constant is now due to the capacitor C_1 with the resistor R_1 in parallel with $R_2 + R_3$

$$T = (R_1 (R_2 + R_3)/(R_1 + R_2 + R_3) C_1$$

$$\Rightarrow t2 = 308 \ \mu s \ \underline{\approx \ 310 \ \mu s}$$



3 - SUMMARY

The 10/700 μ s surge waveform given by the CCITT recommendation is a voltage wave produced by the generator in open circuit. This curve is very important as a test reference for telecommunication equipment.

The protection function designers or users have to know the actual current waveform flowing through the protector in order to optimize it. The 10/700 μ s CCITT generator gives a 5/310 μ s current wave when its outputs are in short circuit. (In the case of a crowbar device, for example Trisil).

For certain cases the resistor R3 is equal to zero and then the duration time becomes 160 μ s.

Please note that in certain documents we find a $8/320 \mu s$ current wave which represents the same surge test.

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